



Part No.: U3535C2VGE10

Product picture



Product introduction

This series of deep uv packaging products are specially designed for applications with high radiation power and directivity requirements. The surface of the packaging body in the form of a patch device, and the use of special uv glass, so as to optimize the product life and performance. It can be used in plant lighting, fluorescence analyzer, medical testing, food and pharmaceutical processing, sterilization and other fields.

Features

- ✧ Ceramic packaging
- ✧ Standard SMD process
- ✧ In line with the ROHS standard

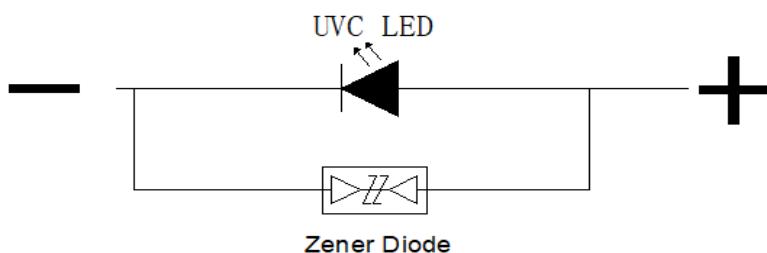
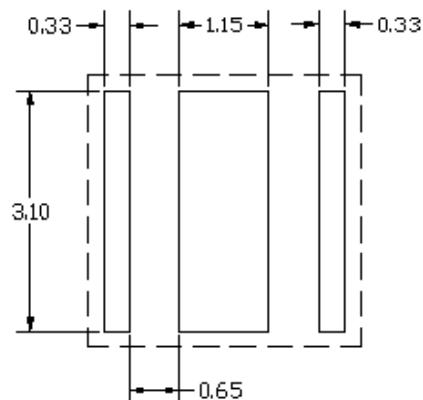
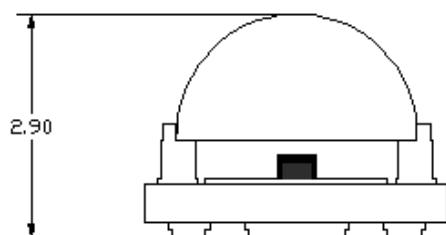
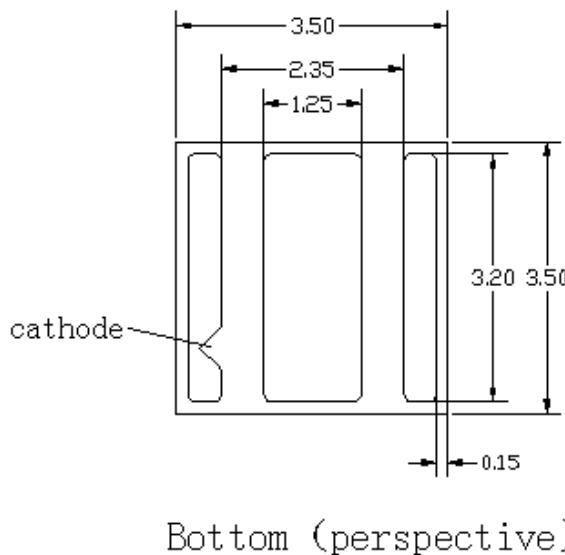
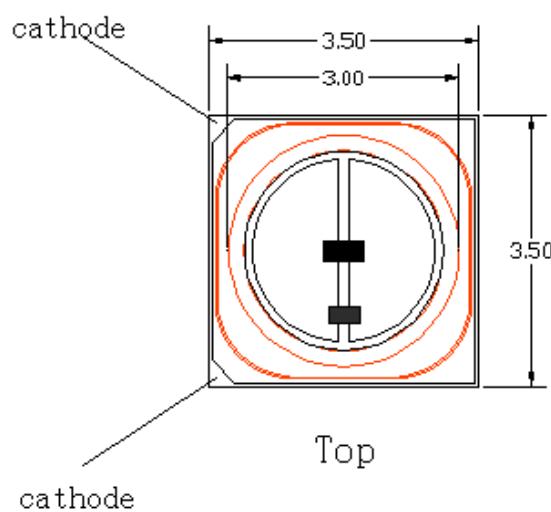
Contents

Outline dimensions	3
Photoelectric properties	4
Limit service condition	4
Photoelectric parameter curve	5
Packaging.....	7
Reliability test.....	9
Recommended reflow temperature curve formula	9



Part No.: U3535C2VGE10

Outline dimensions: (Unit: mm, The tolerance $\pm 0.1\text{mm}$)





Part No.: U3535C2VGE10

Photoelectric properties (Ta = 25°C)

Parameter	Forward current	Symbol	Min.	Typ	Max	Unit
The peak wavelength	If=30mA	λp	270	275	280	nm
Output Radiated power		P _{opt}	--	4.5	--	mW
Forward Voltage		Vf	5	--	7.5	V
FWHM		Δ λ	--	9	--	nm
Viewing Angle		2θ _{1/2}	--	45	--	°
Thermal resistance (T _j -T _{sp})		R _{th}	--	55	--	°C/W
Output Radiated power	If=60mA	P _{opt}	--	6.5	--	mW

Instructions: T_c=25°C; The tolerance of Forward voltage: ±0.1V; The tolerance of Radiation flux: ±8%; The tolerance of peak wavelength : ±3nm.

Limit service condition

Parameter	Symbol	Unit	Range
Forward current	If	mA	≤60
Junction temperature	T _j	°C	≤90
Working temperature	Topr	°C	-30-60
The welding conditions	Tsol	-	260°C<5seconds



Part No.: U3535C2VGE10

Photoelectric parameter curve :

Fig.1 Relative Radiant Power VS Forward Current($T_a=25^{\circ}\text{C}$) Fig.2 Forward Current VS Forward Voltage ($T_a=25^{\circ}\text{C}$)

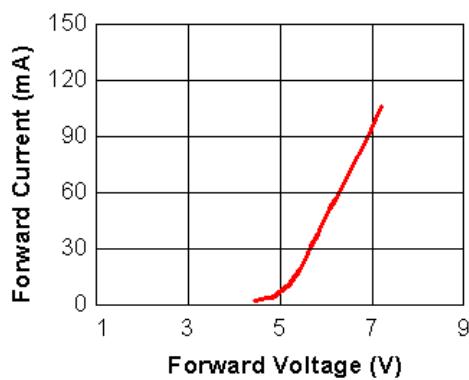
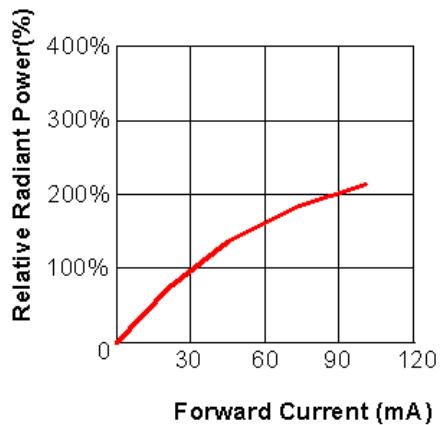


Fig.3 Forward Voltage VS Ambient Temperature

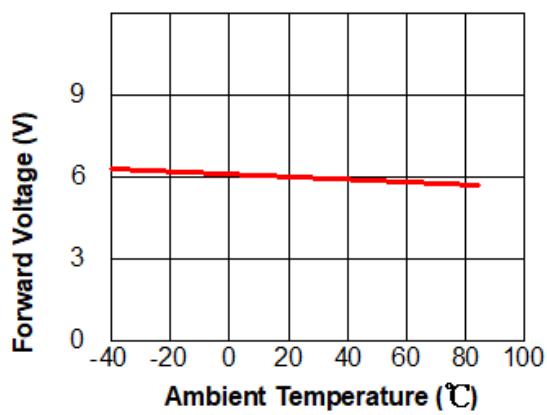
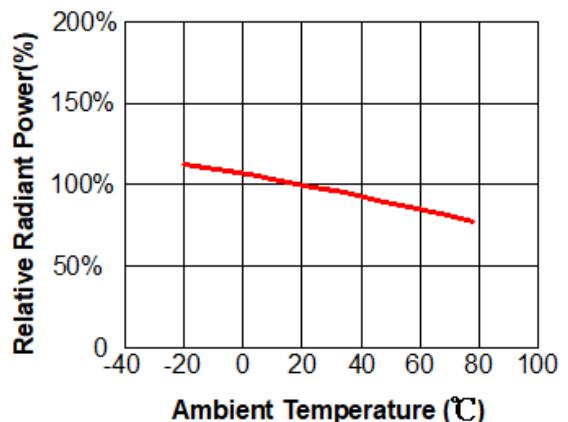


Fig.4 Relative Radiant Power VS Ambient Temperature





Part No.: U3535C2VGE10

Fig.5 Peak Wavelength VS Forward Current

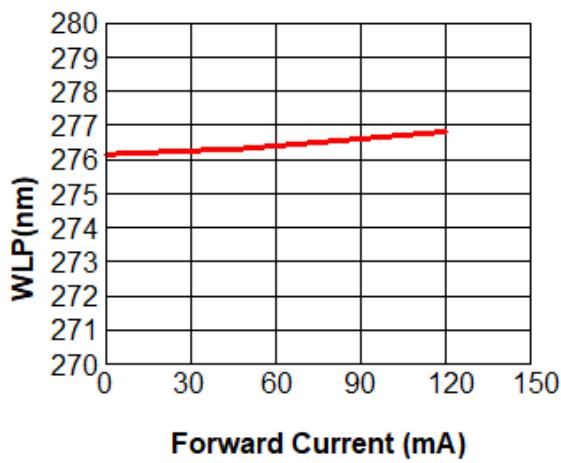
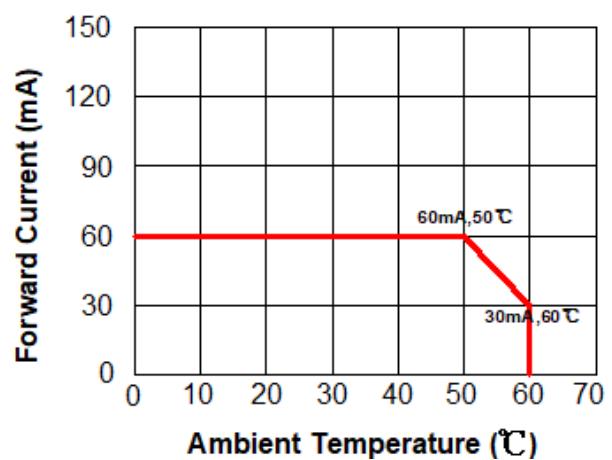


Fig.6 Forward Current VS Ambient Temperature



Packing

Fig.7 Relative Intensity VS WLP

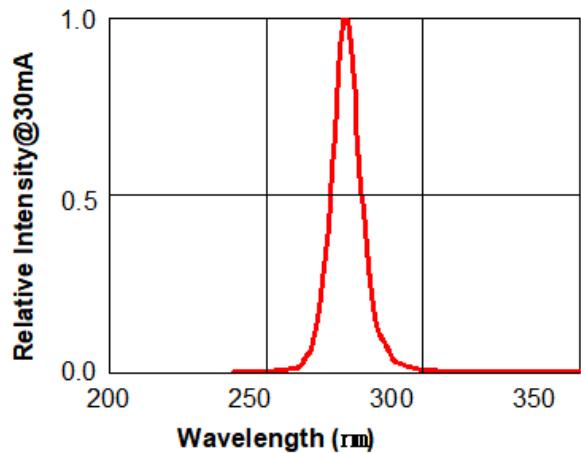
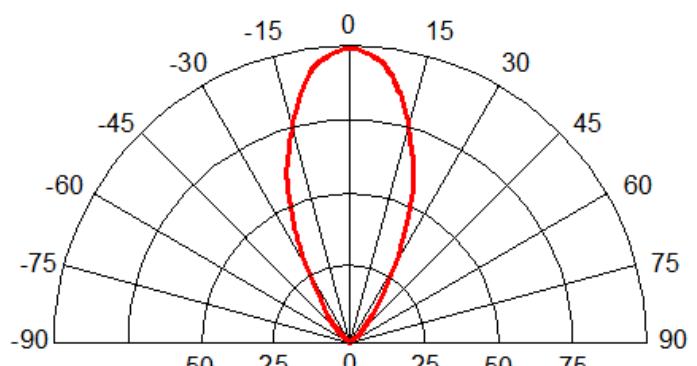


Fig.8 Radiation pattern@30mA

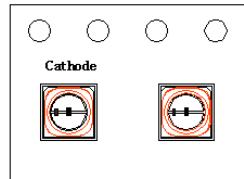
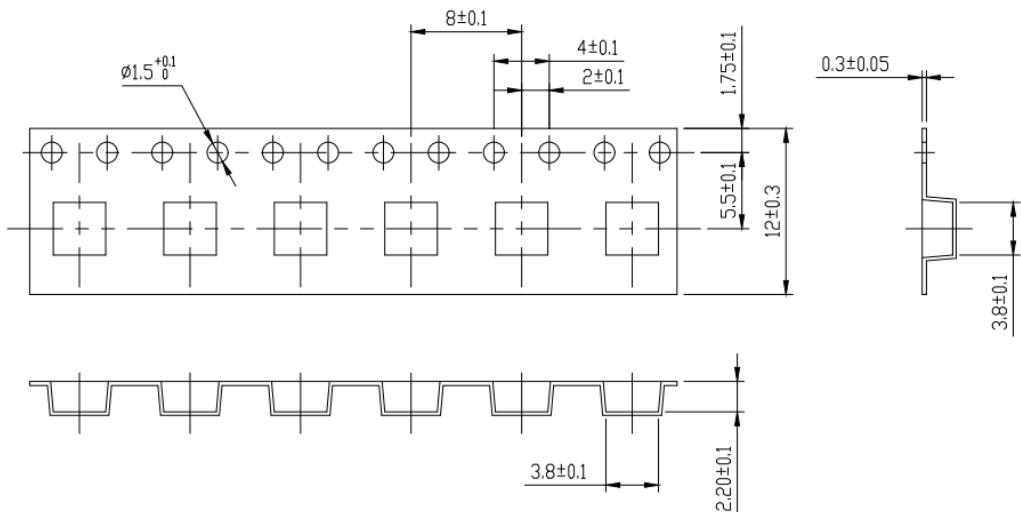




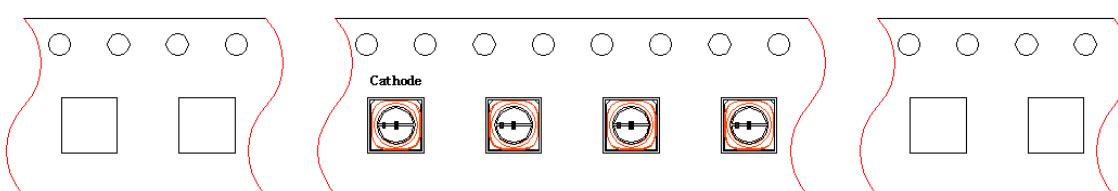
Part No.: U3535C2VGE10

Packing

(Unit: mm)



The End



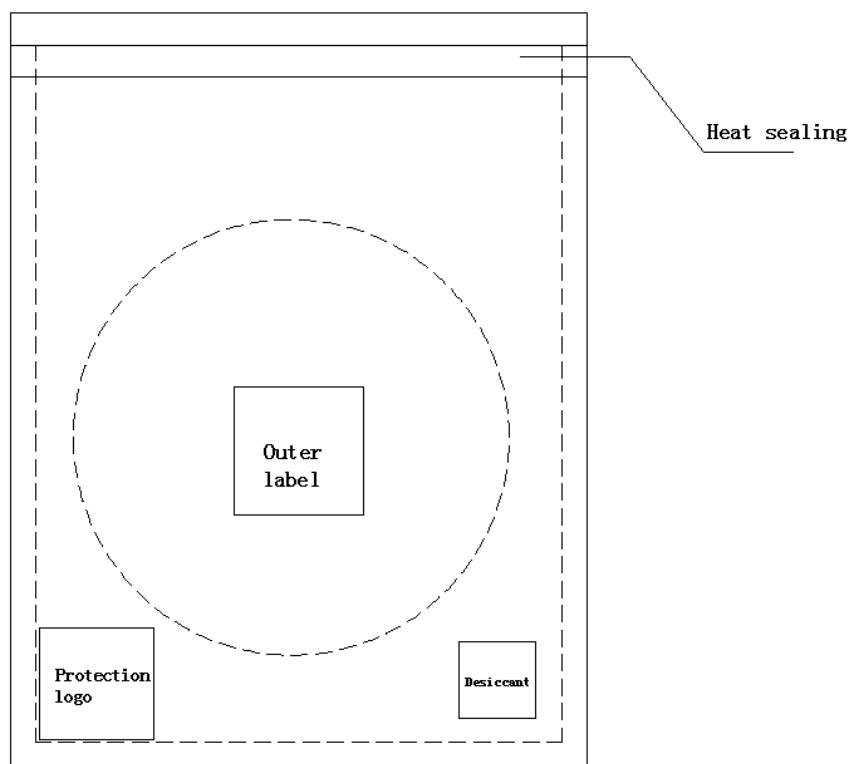
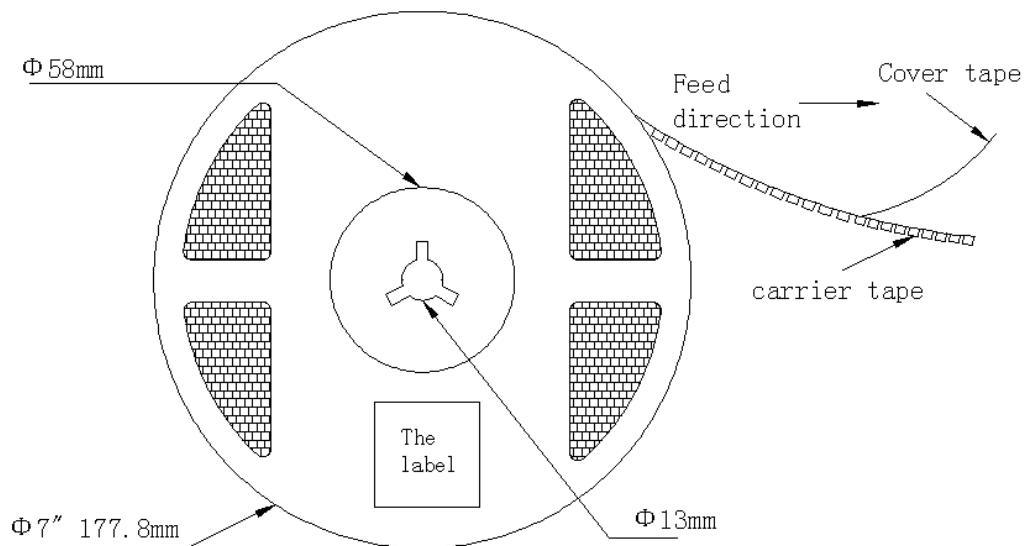
The blank space With 200mm

A roll of 500PCS

The blank space With 400mm



Part No.: U3535C2VGE10



Notice: Please refer to the label value for the actual number of products in each roll, but the total number will not exceed 500.



Part No.: U3535C2VGE10

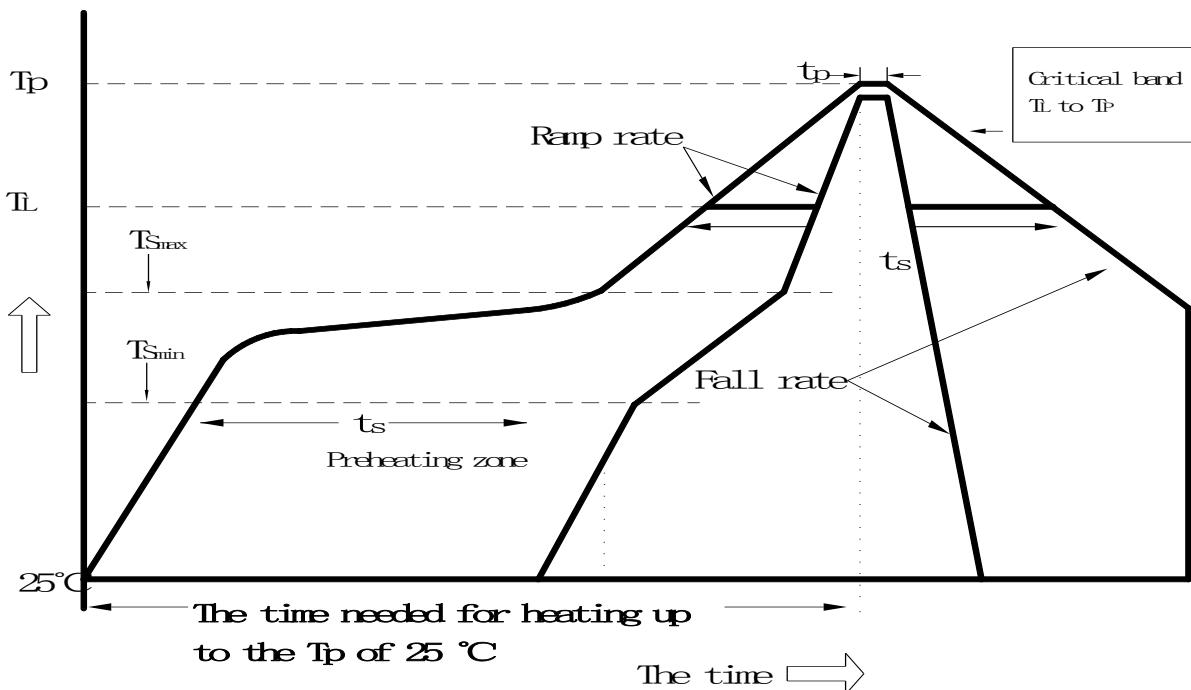
Reliability test

Test	Test Conditions	Failure Criterion
Normal temperature life test	25°C, 30mA, 1000Hours	Forward voltage, $V_f > 110\%$
High temperature storage	100°C, 1000Hours	
Low temperature storage	-40°C, 1000Hours	
Temperature cycle (100times)	-40°C (30mins) ~ +25°C (5mins) +100°C(30mins) ~ +25°C (5mins)	$P_{opt} < 70\%$

Notice:

Test the device at room temperature

Recommend suitable temperature curve formula





Part No.: U3535C2VGE10

Temperature curve characteristics	Lead-free solder
Ramp rate (TSmax to TP)	Max 3°C/S
Preheat: minimum temperature(Tsmin)	150°C
Preheat: maximum temperature(Tsmax)	200°C
Maintain a higher temperature: temperature (TL)	60-180 S
Liquid temperature (TL)	217°C
Maintain a higher temperature: time (TL)	60-150 S
Tp/temperature	260°C
Specify the time within 5°C of the actual peak temperature	20-40 S
The slope rate (Tp to TL)	Max 6°C/S
The time needed for heating up to theTp of 25 °C	Max 8 min